

Sample &

Buy



DRV120

Reference

E Design

SLVSBG3B – JUNE 2012 – REVISED JULY 2015

DRV120 Power-Saving Current Controlled Solenoid Driver

Technical

Documents

1 Features

- Integrated MOSFET With PWM to Control Solenoid Current
 - Integrated Sense Resistor for Regulating Solenoid Current
- Fast Ramp-Up of Solenoid Current to Guarantee Activation
- Solenoid Current is Reduced in Hold Mode for Lower Power and Thermal Dissipation
- Peak Current, Keep Time at Peak Current, Hold Current, and PWM Clock Frequency Can Be Set Externally. They Can Also Be Operated at Nominal Values Without External Components.
- Internal Supply Voltage Regulation
 - Up to 28-V External Supply
- Protection
 - Thermal Shutdown
 - Undervoltage Lockout (UVLO)
 - Maximum Ramp Time
 - Optional STATUS Output
- Operating Temperature Range: –40°C to 105°C
- 8-Pin and 14-Pin TSSOP Package Options

2 Applications

- Electromechanical Drivers: Solenoids, Valves, Relays
- White Goods, Solar, Transportation

3 Description

Tools &

Software

The DRV120 device is a PWM current driver for solenoids. The device is designed to regulate the current with a well-controlled waveform to guarantee activation and to reduce power dissipation at the same time. The solenoid current is ramped up fast to ensure opening of the valve or relay. After the initial ramping, solenoid current is kept at peak value to ensure the correct operation, after which it is reduced to a lower hold level in order to avoid thermal problems and reduce power dissipation.

Support &

Community

The peak current duration is set with an external capacitor. The current ramp peak and hold levels, as well as PWM frequency, can independently be set with external resistors. External setting resistors can also be omitted, if the default values for the corresponding parameters are suitable for the application.

The DRV120 can operate from an external 6-V to 28-V supply.

	I _{SOLENOID} vs Time	
I _{PEAK} —		
I _{HOLD}		
		→
^{EN} ∱	t _{KEEP}	ť

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)						
DRV120	TSSOP (14)	5.00 mm × 4.40 mm						
DRV120	TSSOP (8)	3.00 mm × 4.40 mm						

 For all available packages, see the orderable addendum at the end of the data sheet.

Table of Contents

1		tures 1
2	Арр	lications 1
3	Des	cription 1
4	Rev	ision History 2
5	Pin	Configuration and Functions 3
6	Spe	cifications 4
	6.1	Absolute Maximum Ratings 4
	6.2	ESD Ratings 4
	6.3	Recommended Operating Conditions 4
	6.4	Thermal Information 4
	6.5	Electrical Characteristics 5
	6.6	Typical Characteristics 6
7	Deta	ailed Description7
	7.1	Overview
	7.2	Functional Block Diagram 7
	7.3	Feature Description7

	7.4	Device Functional Modes	9
8	App	lication and Implementation	10
	8.1	Application Information	10
	8.2	Typical Application	10
9	Pow	er Supply Recommendations	12
10	Lay	out	12
	10.1	Layout Guidelines	12
	10.2	Layout Example	12
11	Dev	ice and Documentation Support	13
	11.1	Documentation Support	13
	11.2	Community Resources	13
	11.3	Trademarks	13
	11.4	Electrostatic Discharge Caution	13
	11.5	Glossary	13
12		hanical, Packaging, and Orderable mation	13

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (August 2012) to Revision B

 Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

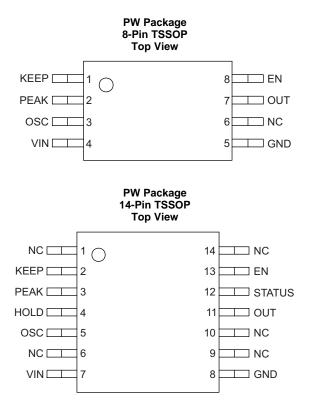
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Page



DRV120

5 Pin Configuration and Functions



Pin Functions

	PIN		1/0	DESCRIPTION				
NAME	8-PIN PW ⁽¹⁾	14-PIN PW	I/O	DESCRIPTION				
EN	8	13	Ι	Enable				
GND	5	8		Ground				
HOLD	-	4	Ι	I Hold current set				
KEEP	1	2	I	Keep time set				
NC	6	1, 6, 9, 10, 14	_	No connect				
OSC	3	5	Ι	PWM frequency set				
OUT	7	11	0	Controlled current sink				
PEAK	2	3	Ι	Peak current set				
STATUS	-	12	0	Open-drain fault indicator				
VIN	4	7	I	6-V to 28-V supply				

(1) In the 8-pin package, the HOLD pin is not bonded out. For this package, the HOLD mode is configured to default (internal) settings.

Specifications 6

6.1 Absolute Maximum Ratings⁽¹⁾⁽²⁾

		MIN	MAX	UNIT
VIN	Input voltage	-0.3	28	V
	Voltage on EN, STATUS, PEAK, HOLD, OSC, SENSE, RAMP	-0.3	7	V
	Voltage on OUT	-0.3	28	V
T_J	Operating virtual junction temperature	-40	125	°C
T _{stg}	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values are with respect to network ground pin. (2)

6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	
V _(ESD) Electrostatic discharge	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $pins^{(2)}$	±500	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. (1)

(2)

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
I _{OUT}	Average solenoid DC current			125	mA
V _{IN}	Supply voltage	6	12	26	V
C _{IN}	Input capacitor	1	4.7		μF
L	Solenoid inductance		1		Н
T _A	Operating ambient temperature	-40		105	°C

6.4 Thermal Information

		DR\		
	THERMAL METRIC ⁽¹⁾	PW [T	UNIT	
		8 PINS	14 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	183.8	122.6	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	69.2	51.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	112.6	64.3	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	10.4	6.5	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	110.9	63.7	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics

 $V_{IN} = 14 \text{ V}, T_A = -40^{\circ}\text{C}$ to 105°C, over operating free-air temperature range (unless otherwise noted)

SUPPLY I _Q CURRENT R _{OUT} f _{PWM}	Standby current Quiescent current DRIVER OUT to GND resistance	$EN = 0, V_{IN} = 14 V$ $EN = 1, V_{IN} = 14 V$		100	150	
CURRENT R _{OUT} f _{PWM}	Quiescent current DRIVER			100	150	
CURRENT R _{OUT} f _{PWM}	DRIVER	EN = 1, V _{IN} = 14 V			100	
R _{OUT} f _{PWM}		1		300	400	μA
f _{PWM}	OUT to GND resistance				1	-
f _{PWM}		I _{OUT} = 200 mA		1.7	2.5	Ω
-	PWM frequency	OSC = GND	15	20	25	kHz
D _{MAX}	Maximum PWM duty cycle			100		%
D _{MIN}	Minimum PWM duty cycle			9		%
t _D	Start-up delay	Delay between EN going high until driver enabled ⁽¹⁾ , $f_{PWM} = 20 \text{ kHz}$		25	50	μs
CURRENT	CONTROLLER, INTERNAL SETTINGS					
I _{PEAK}	Peak current	PEAK = GND	160	200	240	mA
I _{HOLD}	Hold current	HOLD = GND	40	50	60	mA
CURRENT	CONTROLLER, EXTERNAL SETTINGS					
t _{KEEP} ⁽²⁾	Externally set keep time at peak current	C _{KEEP} = 1 µF		75		ms
I _{PEAK} Externally se	Externally set peak current	$R_{PEAK} = 50 \text{ k}\Omega$		250		mA
	Externally set peak current	R _{PEAK} = 200 kΩ		83		
Extorpally a	Externally set hold current	$R_{HOLD} = 50 \text{ k}\Omega$		100		mA
HOLD	Externally set hold current	$R_{HOLD} = 200 \text{ k}\Omega$	33			
1		$R_{OSC} = 50 \text{ k}\Omega$		60		
f _{PWM}	Externally set PWM frequency	$R_{OSC} = 200 \text{ k}\Omega$	20			kHz
LOGIC INP	UT LEVELS (EN)					
V _{IL}	Input low level				1.3	V
V _{IH}	Input high level		1.65			V
R _{EN}	Input pullup resistance		350	500		kΩ
LOGIC OU	IPUT LEVELS (STATUS)				·	
V _{OL}	Output low level	Pulldown activated, I _{STATUS} = 2 mA			0.3	V
IIL	Output leakage current	Pulldown deactivated, V(STATUS) = 5 V			1	μA
UNDERVO	TAGE LOCKOUT	·	•			
V _{UVLO}	Undervoltage lockout threshold			4.6		V
THERMAL	SHUTDOWN	•			1	
T _{TSD}	Junction temperature shutdown threshold			160		°C
T _{TSU}	Junction temperature start-up threshold			140		°C

(1) Logic HIGH between 4 V and 7 V. Note: absolute maximum voltage rating is 7 V.

(2) Either internal or external t_{KEEP} time setting is selected to be activated during manufacturing of production version of DRV120.



6.6 Typical Characteristics

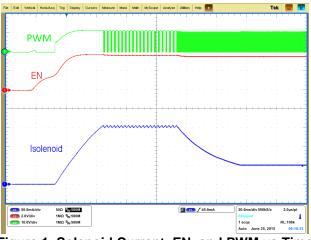


Figure 1. Solenoid Current, EN, and PWM vs Time

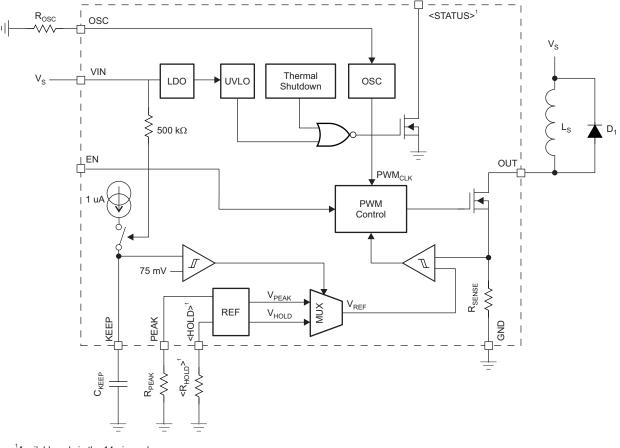


7 Detailed Description

7.1 Overview

The DRV120 device provides a PWM current converter for use with solenoids. The device provides a quick ramp to a high peak current value in order to ensure opening of the valve or relay. The peak current is held for a programmable time and then released to a lower value to maintain the open state of the valve or relay while reducing the total current consumption. Peak current duration, peak current amount, hold current amount (in the 14-pin package), and PWM frequency can all be controlled by external components or used at default levels by omitting these components (except peak current duration). Enable and disable of the switch is controlled by the EN pin which has an internal pullup to V_{IN} . The DRV120 also features a wide V_{IN} range from 6 V to 28 V. Finally, the 14-pin package features an open-drain pulldown path on the STATUS pin which is enabled as long as undervoltage lockout or thermal shutdown has not triggered.

7.2 Functional Block Diagram



¹Available only in the 14-pin package

7.3 Feature Description

The DRV120 controls the current through the solenoid as shown in Figure 2. Activation starts when EN pin voltage is pulled high either by an external driver or internal pullup. In the beginning of activation, DRV120 allows the load current to ramp up to the peak value I_{PEAK} and it regulates it at the peak value for the time, t_{KEEP} , before reducing it to I_{HOLD} . The load current is regulated at the hold value as long as the EN pin is kept high. The initial current ramp-up time depends on the inductance and resistance of the solenoid. Once EN pin is driven to GND, DRV120 allows the solenoid current to decay to zero.

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Feature Description (continued)

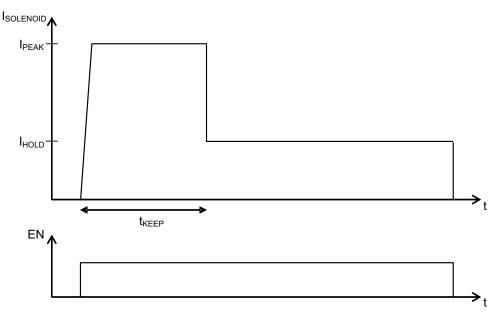


Figure 2. Typical Current Waveform Through the Solenoid

 t_{KEEP} is set externally by connecting a capacitor to the KEEP pin. A constant current is sourced from the KEEP pin that is driven into an external capacitor resulting in a linear voltage ramp. When the KEEP pin voltage reaches 75 mV, the current regulation reference voltage, V_{REF} , is switched from V_{PEAK} to V_{HOLD} . Dependency of t_{KEEP} from the external capacitor size can be calculated by:

$$t_{\text{KEEP}}\left[s\right] = C_{\text{KEEP}}\left[F\right] \cdot 75 \cdot 10^{3} \left[\frac{s}{F}\right]$$

(1)

The current control loop regulates, cycle-by-cycle, the solenoid current by using an internal current-sensing resistor and MOSFET switch. During the ON-cycle, current flows from OUT pin to GND pin through the internal switch as long as voltage across the current-sensing resistor is less than V_{REF} . As soon as the current sensing voltage is above V_{REF} , the internal switch is immediately turned off until the next ON-cycle is triggered by the internal PWM clock signal. In the beginning of each ON-cycle, the internal switch is turned on and stays on for at least the time determined by the minimum PWM signal duty cycle, D_{MIN} .

 I_{PEAK} and I_{HOLD} depend on fixed resistance values R_{PEAK} and R_{HOLD} approximately as shown in Figure 3. If the PEAK pin is connected to ground or if R_{PEAK} or R_{HOLD} is below 33.33 k Ω (typical value), then I_{PEAK} is at its default value (internal setting) of 200 mA for I_{PEAK} and 50 mA for I_{HOLD} . The I_{PEAK} value can alternatively be set by connecting an external resistor to ground from the PEAK pin. For example, if a 50-k Ω (= R_{PEAK}) resistor is connected between PEAK and GND, then the externally set I_{PEAK} level will be 250 mA. If $R_{PEAK} = 200 \ k\Omega$ is, then the externally set I_{PEAK} level will be 250 mA by default. In the 14-pin package, external settings of I_{HOLD} works in the same way as I_{PEAK} . External settings for I_{PEAK} and I_{HOLD} are independent of each other. Approximate I_{PEAK} and I_{HOLD} values can be calculated by using Equation 2 and Equation 3.

$$I_{PEAK} = \frac{250\text{mA}}{\text{R}_{PEAK}} \cdot 66.67\text{k}\Omega; 66.67\text{k}\Omega < \text{R}_{PEAK} < 550\text{k}\Omega$$
(2)
$$I_{HOLD} = \frac{100\text{mA}}{\text{R}_{HOLD}} \cdot 66.67\text{k}\Omega; 66.67\text{k}\Omega < \text{R}_{HOLD} < 250\text{k}\Omega$$
(3)



Feature Description (continued)

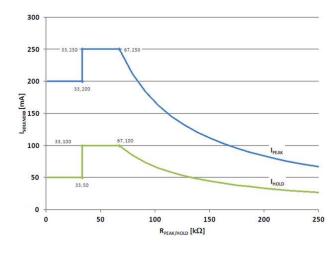


Figure 3. PEAK and HOLD Mode Current Settings

Frequency of the internal PWM clock signal, PWM_{CLK}, that triggers each ON-cycle can be adjusted by external resistor, R_{OSC} , connected between OSC and GND. Frequency as a function of resistor value is shown in Figure 4. Default frequency is used when OSC is connected to GND directly. PWM frequency as a function of external fixed adjustment resistor value (greater than 66.67 k Ω) is given in Equation 4.

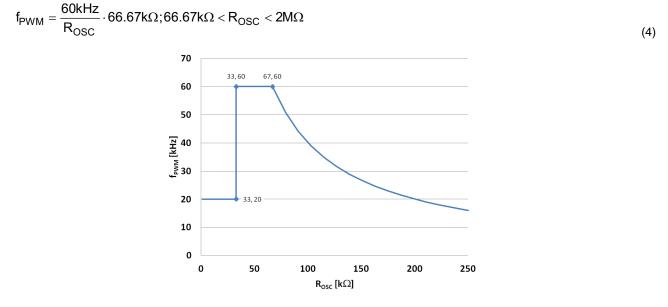


Figure 4. PWM Clock Frequency Setting

Open-drain STATUS output is deactivated if either undervoltage lockout or thermal shutdown blocks have triggered.

7.4 Device Functional Modes

The DRV120 transitions through three different states. The first is the OFF state, where the EN pin is low and the PWM output is off. The second is the PEAK state, which begins when the EN pin is pulled high by an external controller or internal pullup, and ends once t_{KEEP} has been reached. During this state, the PWM operates in order to reach the I_{PEAK} set by the R_{PEAK} . Finally, once t_{KEEP} has been reached, the PWM continues to operate, but at the I_{HOLD} level. This continues until the EN pin is forced low again and the PWM turns off.

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DRV120 device is designed to operate a solenoid valve or relay. A typical DC input design will be outlined in *Typical Application*. Approximate resistor and capacitor values for the peak current, hold current, and keep time will be derived for a sample application.

8.2 Typical Application

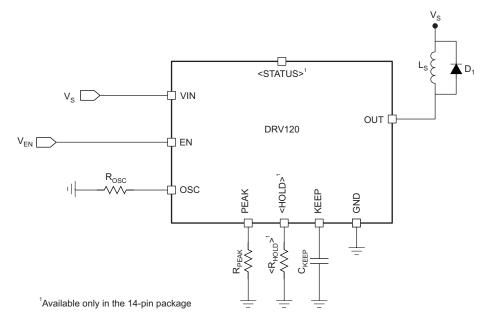


Figure 5. Default Configuration

8.2.1 Design Requirements

The key elements to identify here are the system input voltage, peak current, hold current, and peak keep time values required for the solenoid or relay being used. With these values, approximate R_S , R_{PEAK} , R_{HOLD} (for 14-pin package), and C_{KEEP} values can be determined and the proper FET and diode can be identified. R_{OSC} can be varied in order to tune the circuit to the chosen solenoid or relay.

8.2.2 Detailed Design Procedure

First, with the known peak current, hold current, and peak keep time values known, the R_{PEAK} , R_{HOLD} (for 14-pin package), and C_{KEEP} values can be determined. Calculation will proceed based on example values shown in Table 1.

•	
VARIABLE	VALUE
Peak current	150 mA
Hold current	50 mA
Keep time	100 ms

Table 1. Sample Application Values

 R_{PEAK} and R_{HOLD} (if applicable) can be determined using Equation 2 and Equation 3. For the sample values, R_{PEAK} is set to 111 k Ω and R_{HOLD} can be shorted to GND. TI recommends that a 0- Ω resistor is used for prototyping in case changes to this value are desired.

Next, C_{KEEP} can be set based on Equation 1, 1.33 μ F for the sample values. R_{OSC} can initially be shorted to GND, but again a 0- Ω resistor is recommended for prototyping. Additionally, a filter on the SENSE line may be added if it will be in a high-noise environment and is recommended for prototyping. Typical values for this are 1 k Ω and 100 pF.

Finally, a current recirculation diode must be chosen based on the current values defined in Table 1. The current recirculation diode should be a fast recovery diode.

8.2.3 Application Curves

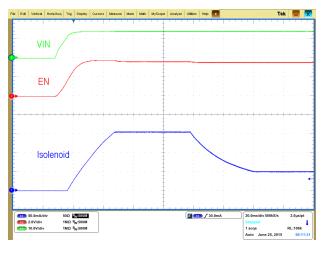




Figure 6. $I_{SOLENOID}$, EN, and V_{IN} vs Time



9 Power Supply Recommendations

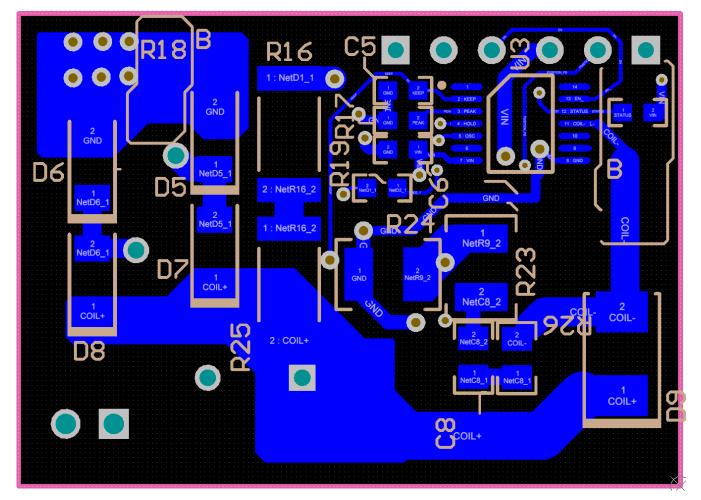
The input supply range must be at least 6 V and should be below 26 V. An input capacitor of 4.7 μ F (typical) is required as well. Current requirements will be set by the required current from the solenoid.

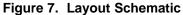
10 Layout

10.1 Layout Guidelines

The trace for the solenoid or relay current should be wide in order to prevent any unexpected voltage drop. Diode placement should not be far from the inductor and both should be placed close to the output.

10.2 Layout Example







11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation, see the following:

Current Controlled Driver for 230V AC Solenoids Reference Design, TIDU584

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



17-Oct-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	-	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
DRV120APWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 105	120A	Samples
DRV120PWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 105	120	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

17-Oct-2014

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All ulmensions are norminal	*All	dimensions	are	nominal
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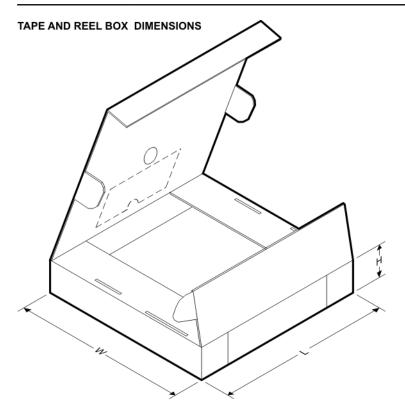
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DRV120APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

12-Dec-2015



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DRV120APWR	TSSOP	PW	14	2000	367.0	367.0	35.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW0008A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.

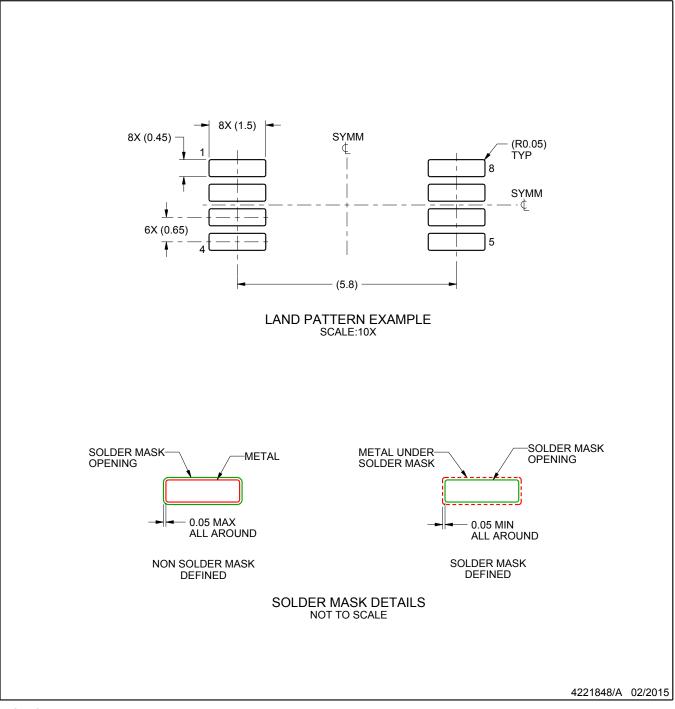


PW0008A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0008A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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